

DG1208ETE+T Datasheet



DiGi Electronics Part Number DG1208ETE+T-DG

Manufacturer Analog Devices Inc./Maxim Integrated

Manufacturer Product Number DG1208ETE+T

Description LOW LEAKAGE, HIGH VOLTAGE 8:1 MU

Detailed Description 1 Circuit IC Switch 8:1 1600hm 16-TQFN (4x4)

https://www.DiGi-Electronics.com



Tel: +00 852-30501935

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Purchase and inquiry

Manufacturer Product Number:	Manufacturer:
DG1208ETE+T	Analog Devices Inc./Maxim Integrated
Series:	Product Status:
	Active
Switch Circuit:	Multiplexer/Demultiplexer Circuit:
SP8T - Open	8:1
Number of Circuits:	On-State Resistance (Max):
1	1600hm
Channel-to-Channel Matching (ΔRon):	Voltage - Supply, Single (V+):
100hm	
Voltage - Supply, Dual (V±):	Switch Time (Ton, Toff) (Max):
±5V ~ 20V	400ns, 400ns
-3db Bandwidth:	Charge Injection:
200MHz	0.5pC
Channel Capacitance (CS(off), CD(off)):	Current - Leakage (IS(off)) (Max):
4pF, 15pF	1nA
Crosstalk:	Operating Temperature:
-80dB @ 1MHz	-40°C ~ 85°C
Mounting Type:	Package / Case:
Surface Mount	16-WQFN Exposed Pad
Supplier Device Package:	
16-TQFN (4x4)	

Environmental & Export classification

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
ECCN:	HTSUS:
EADOO	95/2 20 0001

Click here to ask about the production status of specific part numbers.

DG1208/DG1209

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

General Description

The DG1208 and DG1209 are low-leakage, low-charge-injection, single 8-channel or dual 4-channel multiplexing switch devices. The DG1208 uses three selection inputs A2, A1, and A0 to determine the switching logic; the DG1209 uses two selection inputs A1 and A0. On both devices, an enable (EN) input is used to enable or disable the device.

The low capacitance and low charge injection of the DG1208/DG1209 make them ideal for automatic test equipment systems, data acquisition systems and sample-and-hold systems where low glitch and fast settling time are required.

The DG1208/DG1209 are available in 4mm x 4mm 16-lead TQFN or 16-lead TSSOP packages. The devices are specified for operation over the -40°C to +85°C temperature range.

Applications

- Automatic Test Equipment Systems
- Data Acquisition Systems
- Sample-and-Hold Systems
- Communication Systems
- Audio and Video Routing

Benefits and Features

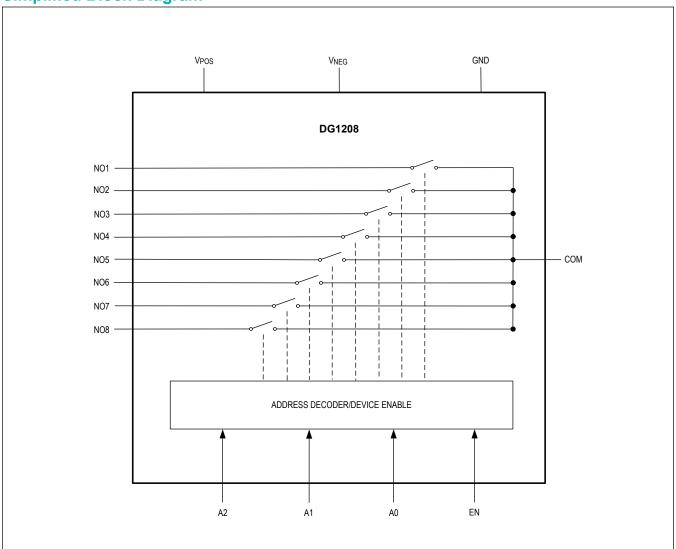
- Distortion-Free Measurement
 - 100Ω (typ) On Resistance
 - ≤ 1nA (max) On/Off-Leakage Current at +85°C
 - ≤ 0.5pC (typ) Charge Injection
- Wide Supply Range with Low Supply Current
 - 40µA (typ) Quiescent Current at Room Temperature
 - Fully Specified with ±15V Bipolar Supplies or +12V Single Supply
 - · Rail-to-Rail Operation
- Flexible Design Option
 - · GPIO-Compatible Control Inputs
 - · EN Input to Enable/Disable Device
 - Available in both 16-TQFN and 16-TSSOP Packages
 - -40°C to +85°C Temperature Range

Ordering Information appears at end of data sheet.

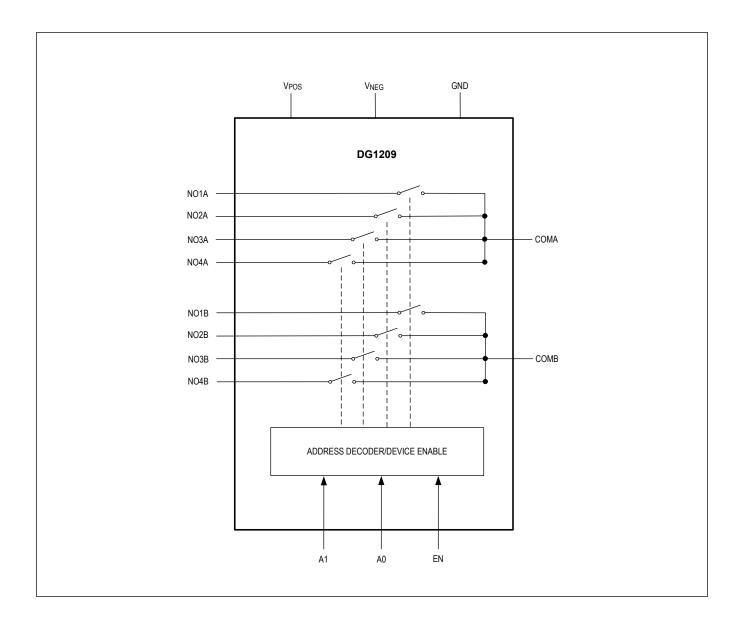


Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Simplified Block Diagram



Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers



Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Absolute Maximum Ratings

V _{POS} to GND	0.3V to +20.5V
V _{NEG} to GND	20.5V to +0.3V
V _{POS} to V _{NEG}	0.3V to +41V
A_, EN to GND	0.3V to (V _{POS} + 0.3V)
NO_, COM_ to GND	$(V_{NEG} - 0.3V)$ to $(V_{POS} + 0.3V)$
Continuous Current Into Any Pin	±30mA
Continuous Power Dissipation (1	6 TQFN)
Single-Layer Board ($T_A = +70$	0°C, derate 16.90mW/°C above
+70°C)	1349.10mW
Multilayer Board ($T_A = +7$	0°C, derate 25mW/°C above
+70°C)	2000mW

Single-Layer Board (T _A = +70°C, derate 9.40mW/°C above	тW
+70°C)754.70m\	
Multilayer Board (T _A = +70°C, derate 11.10mW/°C above	ove
+70°C)888.90m\	ηW
Operating Temperature Range40°C to 85°	
Junction Temperature+150°	0°C
Storage Temperature Range40°C to +150°	
Soldering Temperature (reflow)+260°	0°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Package Information

16 TQFN

Package Code	T1644+4				
Outline Number	21-0139				
Land Pattern Number 90-0070					
THERMAL RESISTANCE, SINGLE-LAYER BOARD					
Junction to Ambient (θ _{JA})	59.30°C/W				
Junction to Case (θ _{JC}) 6°C/W					
THERMAL RESISTANCE, FOUR-LAYER BOARD					
nction to Ambient (θ _{JA}) 40°C/W					
Junction to Case (θ _{JC}) 6°C/W					

16 TSSOP

Package Code	U16+1			
Outline Number	<u>21-0066</u>			
Land Pattern Number	90-0117			
THERMAL RESISTANCE, SINGLE-LAYER BOARD				
Junction to Ambient (θ _{JA}) 106°C/W				
Junction to Case (θ_{JC})	27°C/W			
THERMAL RESISTANCE, FOUR-LAYER BOARD				
Junction to Ambient (θ _{JA}) 90°C/W				
Junction to Case (θ_{JC}) 27°C/W				

For the latest package outline information and land patterns (footprints), go to www.maximintegrated.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a four-layer board. For detailed information on package thermal considerations, refer to www.maximintegrated.com/thermal-tutorial.

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Electrical Characteristics - ±15V Bipolar Supplies

 $(V_{POS} = +15V, V_{NEG} = -15V, GND = 0V, T_A = -40^{\circ}C \text{ to } 85^{\circ}C, \text{ unless otherwise noted.})$

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
POWER SUPPLY						
Positive Power-Supply Voltage	V _{POS}		+5		+20	V
Negative Power-Supply Voltage	V _{NEG}		-20		-5	V
Positive Power-Supply		EN = A_ = 0V		40	70	μΑ
Current	I _{POS}	EN = A_ = 2.4V		40	80	
Negative Power-Supply		EN = A_ = 0V	-1		+1	
Current	INEG	EN = A_ = 2.4V	-1		+1	μA
ANALOG SWITCH						
Analog-Signal Voltage Range	V _{NO} _, V _{COM} _		V _{NEG}		V _{POS}	V
On-Resistance	R _{ON}	V _{COM} = 0V, ±5V, ±10V, I _{COM} = 1mA (<u>Note 2</u>)		100	160	Ω
On-Resistance Match Between Channels	ΔR _{ON}	V _{COM} = 0V, ±5V, ±10V, I _{COM} = 1mA (<u>Note 2</u>)		10	30	Ω
On-Resistance Flatness	R _{FLAT}	V _{COM_} = -5V, 0V, +5V, I _{COM_} = 1mA (<u>Note 3</u>)		17	25	Ω
NO_ Off Capacitance	C _{NO_OFF}	V _{NO} = 0.5V _{P-P} , f _{SW} = 1MHz		4		pF
COM_ Off Capacitance	C _{COM OFF}	$V_{COM} = 0.5V_{P-P}, f_{SW} = 1MHz$		15		pF
COM_ On Capacitance	C _{COM_ON}	$V_{COM} = 0.5V_{P-P}, f_{SW} = 1MHz$		10		pF
NO_ Off-Leakage Current	I _{NO_OFF}	V _{NO} _ = ±10V, V _{COM} _ = ∓10V (<i>Note 4</i>)	-1		+1	nA
COM_ Off-Leakage		DG1208, V _{NO} _ = +1/+10V, V _{COM} _ = +10/+1V (<u>Note 5</u>)	-1		+1	4
Current	ICOM_OFF	DG1209, V _{NO} _ = +1/+10V, V _{COM} _ = +10/+1V (<u>Note 5</u>)	-1		+1	nA
COM_ On-Leakage		DG1208, V _{NO} _ = V _{COM} _ = ±10V	-1		+1	^
Current	ICOM_ON	DG1209, V _{NO} _ = V _{COM} _ = ±10V	-1		+1	nA
DYNAMIC CHARACTER	ISTICS					
Turn-On Time	t _{ON}	<u>Figure 1</u> , V _S = 10V		200	400	ns
Turn-Off Time	t _{OFF}	<u>Figure 1</u> , V _S = 10V		300	400	ns
Break-Before-Make Time	t _{BBM}	<u>Figure 2</u> , V _S = 10V	50			ns
Total Transition Time	t _{TT}	Figure 3, V _S = 10V			400	ns
0.4D D 4 - 2.111		DG1208, <i>Figure 4</i> , R _S = R _L = $50Ω$		200		
-3dB Bandwidth	f _{BW}	DG1209, Figure 4, $R_S = R_L = 50\Omega$		250		MHz
Total Harmonic Distortion Plus Noise	THD+N	Figure 5, R_S = 50Ω, R_L = 10kΩ, V_S = 5 V_{RMS} , f_{SW} = 20Hz to 20kHz		0.1		%
Off-Isolation		Figure 6, $R_S = R_L = 50\Omega$, $V_{NO} = 0.5V_{P-}$ p, $f_{SW} = 1MHz$		-80		dB
Crosstalk		Figure 7, $R_S = R_L = 50\Omega$, $V_{NO} = 0.5V_{P-}$ P, $f_{SW} = 1$ MHz		-80		dB

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Electrical Characteristics - ±15V Bipolar Supplies (continued)

(V_{POS} = +15V, V_{NEG} = -15V, GND = 0V, T_A = -40°C to 85°C, unless otherwise noted.) (*Note 1*)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Charge Injection	C _{INJ}	Figure 8, $R_S = 0\Omega$, $V_S = 0V$		0.5		рС
DIGITAL INPUTS (A_, EN)						
Input Logic High Voltage	V _{IH}		2.4			V
Input Logic Low Voltage	V _{IL}				0.8	V
Input-Leakage Current	I _{IN}		-5		+40	μA

Electrical Characteristics - +12V Single Supply

(V_{POS} = +12V, V_{NEG} = GND = 0V, T_A = -40°C to 85°C, unless otherwise noted.) (<u>Note 1</u>)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS	
POWER SUPPLY							
Positive Power-Supply Voltage	V _{POS}		10	12	20	V	
Positive Power-Supply Current	I _{POS}	EN = A_ = 0V EN = A_ = 2.4V			70 90	μΑ	
ANALOG SWITCH	•						
Analog-Signal Voltage Range	V _{NO} _, V _{COM} _		0		V _{POS}	V	
On-Resistance	R _{ON}	V _{COM} _ = 3V, 6V, 9V, I _{COM} _ = 1mA (<u>Note</u> <u>6</u>)		165	250	Ω	
On-Resistance Match Between Channels	ΔR _{ON}	V _{COM} _ = 3V, 6V, 9V, I _{COM} _ = 1mA (<u>Note</u> <u>6</u>)		18	50	Ω	
On-Resistance Flatness	R _{FLAT}	V _{COM} _ = 3V, 6V, 9V, I _{COM} _ = 1mA (<u>Note</u> <u>6</u>)		15	50	Ω	
NO_ Off Capacitance	C _{NO_OFF}	V _{NO} _ = 0.5V _{P-P} , f _{SW} = 1MHz		4		pF	
COM_ Off Capacitance	C _{COM_OFF}	V _{COM} _ = 0.5V _{P-P} , f _{SW} = 1MHz		15		pF	
COM_ On Capacitance	C _{COM_ON}	V _{COM} _ = 0.5V _{P-P} , f _{SW} = 1MHz		10		pF	
NO_ Off-Leakage Current	I _{NO_OFF}	V _{NO_} = +1/+10V, V _{COM_} = +10/+1V (<u>Note 7</u>)	-1		+1	nA	
COM_ Off-Leakage		DG1208, V _{NO} _= +1/+10V, V _{COM} _= +10/+1V (<u>Note 7</u>)	-1		+1		
Current	ICOM_OFF	DG1209, V _{NO} _= +1/+10V, V _{COM} _= +10/+1V (<u>Note 7</u>)	-1		+1	- nA	
COM_ On-Leakage		DG1208, V _{NO} _ = V _{COM} _ = +1V or +10V	-1		+1	^	
Current	ICOM_ON	DG1209, V _{NO} _ = V _{COM} _ = +1V or +10V	-1		+1	nA	
DYNAMIC CHARACTER	ISTICS						
Turn-On Time	t _{ON}	Figure 1, V _S = 10V		400	600	ns	
Turn-Off Time	toff	Figure 1, V _S = 10V		250	500	ns	
Break-Before-Make Time	t _{BBM}	Figure 2, V _S = 10V	50			ns	
Total Transition Time	t _{TT}	Figure 3, V _S = 10V			700	ns	
-3dB Bandwidth	f _{BW}	DG1208, <u>Figure 4</u> , $R_S = R_L = 50\Omega$ DG1209, <u>Figure 4</u> , $R_S = R_L = 50\Omega$		200 250		MHz	

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Electrical Characteristics - +12V Single Supply (continued)

 $(V_{POS} = +12V, V_{NEG} = GND = 0V, T_A = -40^{\circ}C$ to 85°C, unless otherwise noted.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNITS
Total Harmonic Distortion Plus Noise	THD+N	Figure 5, R _S = 50Ω, R _L = 10kΩ, V _S = $5V_{RMS}$, f _{SW} = 20Hz to 20kHz,		0.1		%
Off-Isolation		Figure 6, R _S = R _L = 50Ω, V_{NO} = 0.5 V_{P-} P, f_{SW} = 1MHz		-80		dB
Crosstalk		Figure 7, $R_S = R_L = 50\Omega$, $V_{NO} = 0.5V_{P-}$ P, $f_{SW} = 1MHz$		-80		dB
Charge Injection	C _{INJ}	Figure 8, $V_S = 6V$, $R_S = 0\Omega$		0.5		pC
DIGITAL INPUTS (A_, EN	۷)					
Input Logic High Voltage	V _{IH}		2.4			V
Input Logic Low Voltage	V _{IL}				8.0	V
Input-Leakage Current	I _{IN}		-5		+30	μA

- **Note 1:** Limits are 100% tested at T_A = +85°C. Limits over the operating temperature range and relevant supply-voltage range are guaranteed by design and characterization.
- Note 2: On Resistance (R_{ON}) and On-Resistance Match Between Channels (ΔR_{ON}) are measured when the output channel is turned on. The output (COM_) is sourced with 1mA current while biased at one of these levels: 0V, ±5V, or ±10V.
- Note 3: On-Resistance Flatness (R_{FLAT}) is measured when the output channel is turned on. The output (COM_) is sourced with 1mA current while biased at one of these levels: -5V, 0V, or +5V.
- Note 4: NO_ Off-Leakage Current (I_{NO_OFF}) is measured when the output channel is switched off while the input (NO_) is biased at +10V and output (COM_) at -10V, or while the input is biased at -10V and output at +10V.
- Note 5: COM_ Off-Leakage Current (I_{COM_OFF}) is measured when the output channel is switched off while the input (NO_) is biased at +1V and output (COM_) at +10V, or while the input is biased at +10V and output at +1V.
- Note 6: On Resistance (R_{ON}), On-Resistance Match Between Channels (ΔR_{ON}), and On-Resistance Flatness (R_{FLAT}) are measured when the output channel is turned on. The output (COM_) is sourced with 1mA current while biased at one of these levels: 3V, 6V. or 9V.
- Note 7: NO_Off-Leakage Current (INO_OFF) and COM_Off-Leakage Current (ICOM_OFF) are measured when the output channel is switched off while the input (NO_) is biased at +1V and output (COM_) at +10V, or while the input is biased at +10V and output at +1V.

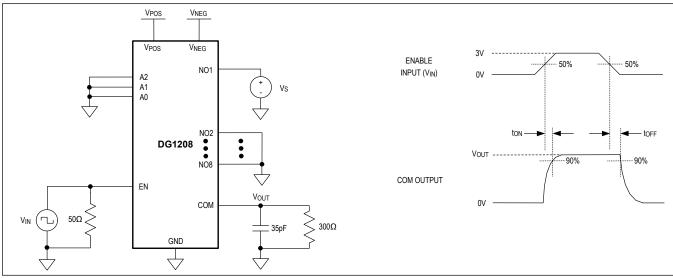


Figure 1. Turn-On Time and Turn-Off Time (Similar Connection for DG1209)

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

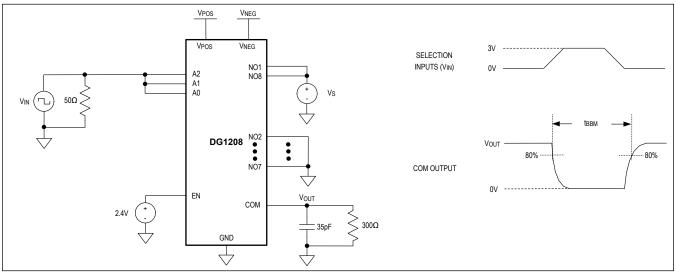


Figure 2. Break-Before-Make Time (Similar Connection for DG1209)

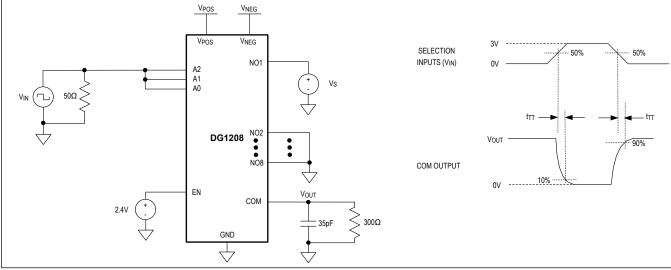


Figure 3. Total Transition Time (Similar Connection for DG1209)

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

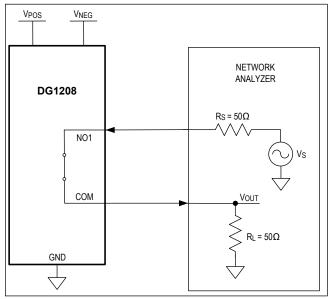


Figure 4. -3dB Bandwidth (Similar Connection for DG1209)

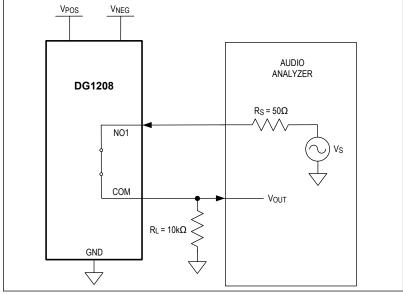


Figure 5. Total Harmonic Distortion Plus Noise (Similar Connection for DG1209)

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

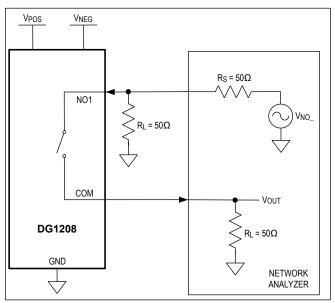


Figure 6. Off Isolation (Similar Connection for DG1209)

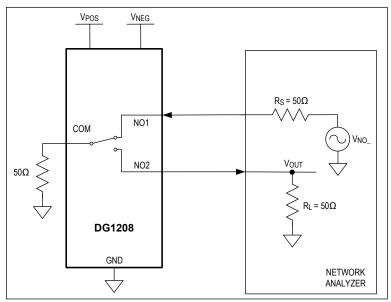


Figure 7. Crosstalk (Similar Connection for DG1209)

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

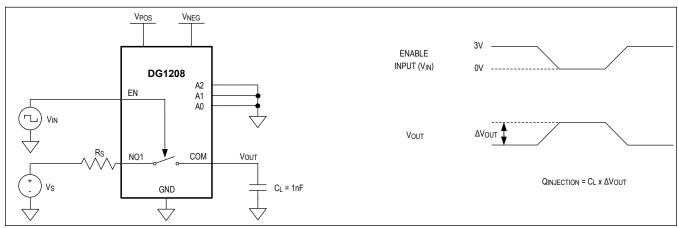
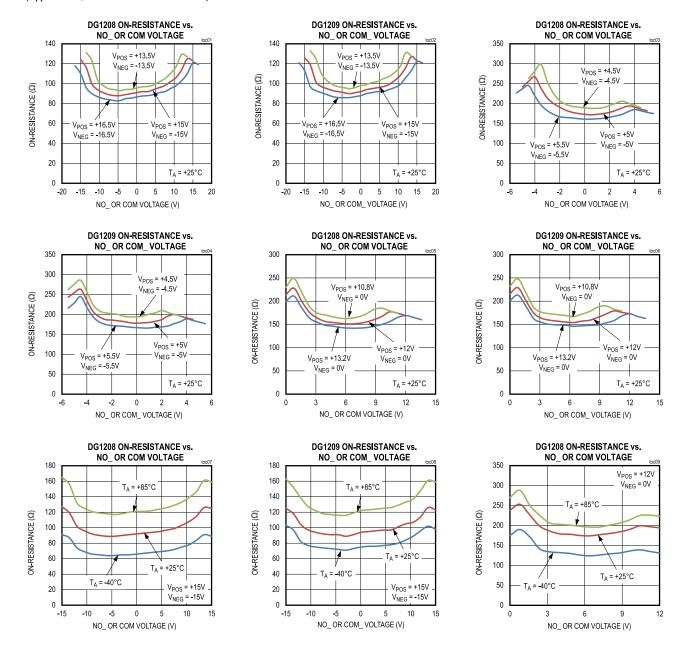


Figure 8. Charge Injection (Similar Connection for DG1209)

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Typical Operating Characteristics

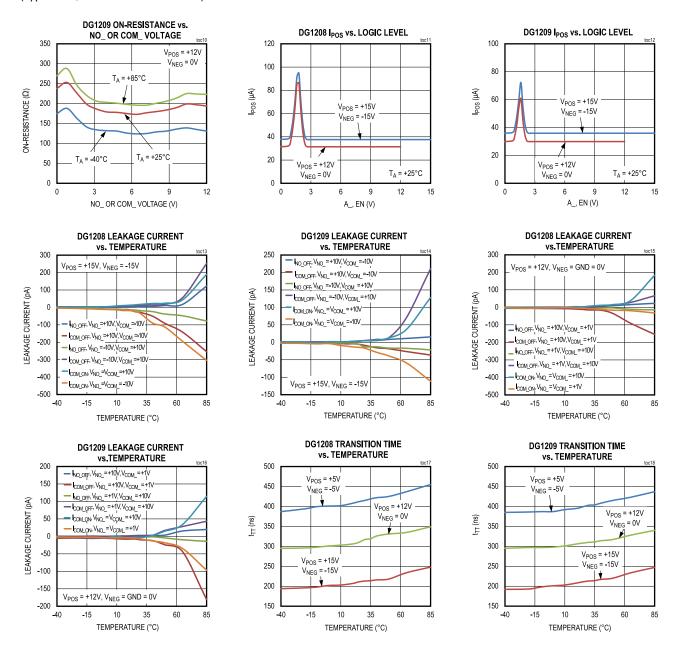
 $(T_A = 25^{\circ}C, unless otherwise noted.)$



Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Typical Operating Characteristics (continued)

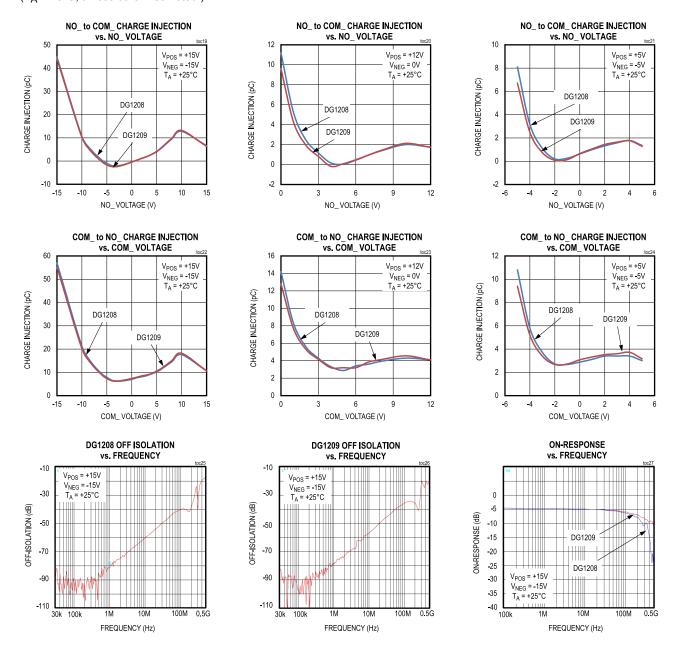
(T_A = 25°C, unless otherwise noted.)



Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Typical Operating Characteristics (continued)

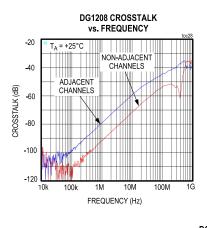
(T_A = 25°C, unless otherwise noted.)

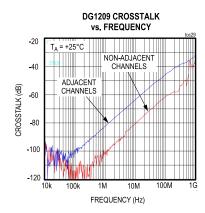


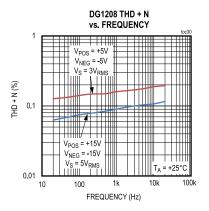
Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

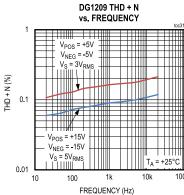
Typical Operating Characteristics (continued)

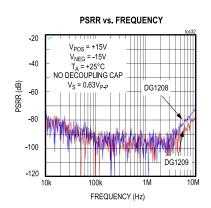
(T_A = 25°C, unless otherwise noted.)







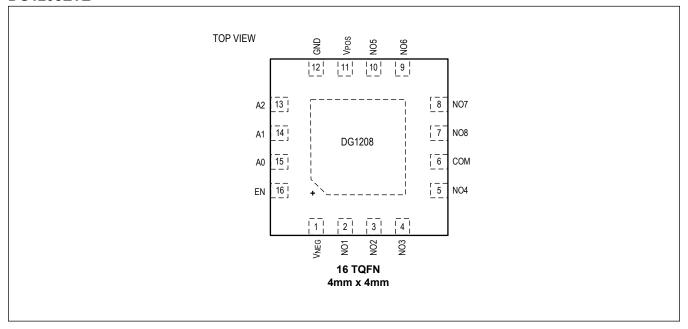




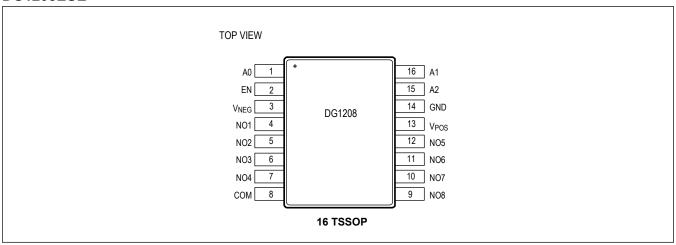
Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Pin Configurations

DG1208ETE+



DG1208EUE+



Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

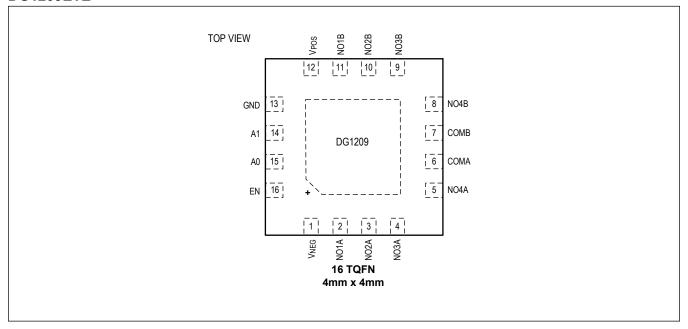
Pin Description

PIN					
DG1208ETE +	DG1208EUE +	NAME	FUNCTION		
POWER SUPP	PLY				
11	13	V _{POS}	Positive Power Supply. Bypass V _{POS} to GND with a minimum 0.1µF ceramic capacitor as close to the pin as possible.		
1	3	V _{NEG}	Negative Power Supply. Bypass V_{NEG} to GND with a minimum $0.1\mu F$ ceramic capacitor as close to the pin as possible. In single-supply applications, connect V_{NEG} to GND.		
12	14	GND	Logic Ground Reference		
EP	-	EP	Exposed Pad. Leave unconnected.		
DIGITAL INPU	TS				
13	15	A2	Logic Address Input. See the <i>Control Logic</i> section for more information.		
14	16	A1	Logic Address Input. See the <i>Control Logic</i> section for more information.		
15	1	A0	Logic Address Input. See the <i>Control Logic</i> section for more information.		
16	2	EN	Enable Input. Drive EN high to enable the multiplexer. Drive EN low to disable all switches. Do not leave EN unconnected.		
ANALOG SWI	тсн				
6	8	COM	Common Bidirectional Analog Signal Terminal. It can be either an input or output.		
7	9	NO8	Normally-Open Bidirectional Analog Signal Terminal 8. It can be either an input or output.		
8	10	NO7	Normally-Open Bidirectional Analog Signal Terminal 7. It can be either an input or output.		
9	11	NO6	Normally-Open Bidirectional Analog Signal Terminal 6. It can be either an input or output.		
10	12	NO5	Normally-Open Bidirectional Analog Signal Terminal 5. It can be either an input or output.		
5	7	NO4	Normally-Open Bidirectional Analog Signal Terminal 4. It can be either an input or output.		
4	6	NO3	Normally-Open Bidirectional Analog Signal Terminal 3. It can be either an input or output.		
3	5	NO2	Normally-Open Bidirectional Analog Signal Terminal 2. It can be either an input or output.		
2	4	NO1	Normally-Open Bidirectional Analog Signal Terminal 1. It can be either an input or output.		

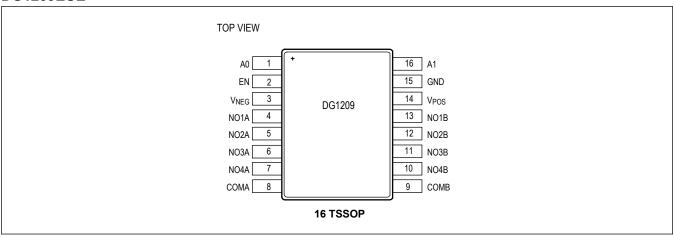
Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Pin Configurations

DG1209ETE+



DG1209EUE+



Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Pin Description

PIN				
DG1209ETE +	DG1209EUE +	NAME	FUNCTION	
POWER SUPP	PLY			
12	14	V _{POS}	Positive Power Supply. Bypass V _{POS} to GND with a minimum 0.1µF ceramic capacitor as close to the pin as possible.	
1	3	V_{NEG}	Negative Power Supply. Bypass V_{NEG} to GND with a minimum 0.1 μ F ceramic capacitor as close to the pin as possible. In single supply applications, connect V_{NEG} to GND.	
13	15	GND	Logic Ground Reference	
EP	-	EP	Exposed Pad. Leave unconnected.	
DIGITAL INPU	TS			
14	16	A1	Logic Address Input. See the <i>Control Logic</i> section for more information.	
15	1	A0	Logic Address Input. See the <i>Control Logic</i> section for more information.	
16	2	EN	Enable Input. Drive EN high to enable the multiplexer. Drive EN low to disable all switches. Do not leave EN unconnected.	
ANALOG SWI	тсн			
7	9	СОМВ	B-Side Common Bidirectional Analog Signal Terminal. It can be either an input or output.	
6	8	COMA	A-Side Common Bidirectional Analog Signal Terminal. It can be either an input or output.	
8	10	NO4B	B-Side Normally-Open Bidirectional Analog Signal Terminal 4. It can be either an input or output.	
9	11	NO3B	B-Side Normally-Open Bidirectional Analog Signal Terminal 3. It can be either an input or output.	
10	12	NO2B	B-Side Normally-Open Bidirectional Analog Signal Terminal 2. It can be either an input or output.	
11	13	NO1B	B-Side Normally-Open Bidirectional Analog Signal Terminal 1. It can be either an input or output.	
5	7	NO4A	A-Side Normally-Open Bidirectional Analog Signal Terminal 4. It can be either an input or output.	
4	6	NO3A	A-Side Normally-Open Bidirectional Analog Signal Terminal 3. It can be either an input or output.	
3	5	NO2A	A-Side Normally-Open Bidirectional Analog Signal Terminal 2. It can be either an input or output.	
2	4	NO1A	A-Side Normally-Open Bidirectional Analog Signal Terminal 1. It can be either an input or output.	

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Detailed Description

The DG1208/DG1209 are single 8-channel or dual 4-channel multiplexing switch devices with low leakage and low charge injection. The low capacitance and low charge injection of the DG1208/DG1209 make them ideal for automatic test equipment systems, data acquisition systems, sample-and-hold systems, and communication systems where low glitch and fast settling time are required.

The DG1208 is a single 8-channel multiplexer. It switches one of the 8 NO_ inputs to a common output COM, as determined by the three selection inputs A2, A1, and A0. The DG1209 is a dual 4-channel multiplexer. It switches a pair of differential NO_ inputs to differential outputs COMA and COMB, as determined by the two selection inputs A1 and A0. See the <u>Control Logic</u> section for more information.

The DG1208/DG1209 operate rail-to-rail and are fully specified for ±15V bipolar supplies or +12V single supply. The EN input on the DG1208/DG1209 is used to enable or disable the device. When EN is low, all channels are switched off. When EN is high, each channel conducts bidirectionally according to the selection inputs.

Control Logic

The DG1208 uses three selection inputs A2, A1, and A0 to determine the switching logic.

Table 1. DG1208 Control Logic

A2	A1	A0	EN	SWITCH ON
X	X	Х	0	Switch Off
0	0	0	1	NO1
0	0	1	1	NO2
0	1	0	1	NO3
0	1	1	1	NO4
1	0	0	1	NO5
1	0	1	1	NO6
1	1	0	1	NO7
1	1	1	1	NO8

The DG1209 uses two selection inputs A1, and A0 to determine the switching logic.

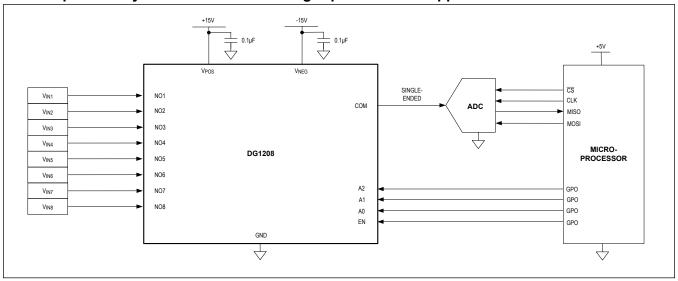
Table 2. DG1209 Control Logic

A1	A0	EN	SWITCH ON
Х	X	0	Switch Off
0	0	1	NO1A, NO1B
0	1	1	NO2A, NO2B
1	0	1	NO3A, NO3B
1	1	1	NO4A, NO4B

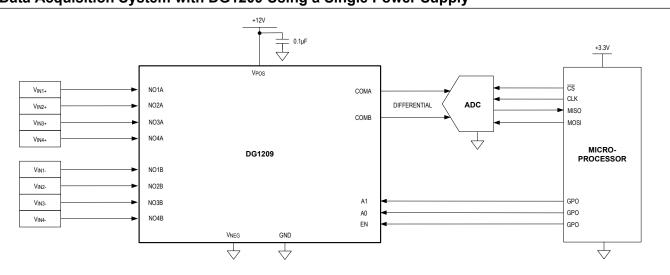
Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Typical Application Circuits

Data Acquisition System with DG1208 Using Bipolar Power Supplies



Data Acquisition System with DG1209 Using a Single Power Supply



Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Ordering Information

PART NUMBER	PIN-PACKAGE	TEMPERATURE
DG1208ETE+	16 TQFN	-40°C to +85°C
DG1208ETE+T	16 TQFN	-40°C to +85°C
DG1208EUE+	16 TSSOP	-40°C to +85°C
DG1208EUE+T	16 TSSOP	-40°C to +85°C
DG1209ETE+	16 TQFN	-40°C to +85°C
DG1209ETE+T	16 TQFN	-40°C to +85°C
DG1209EUE+	16 TSSOP	-40°C to +85°C
DG1209EUE+T	16 TSSOP	-40°C to +85°C

⁺ Denotes a lead(Pb)-free/RoHS-compliant package.

Low-Leakage, Single 8-Channel and Dual 4-Channel, Analog Multiplexers

Revision History

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
0	11/20	Release for Market Intro	_
1	8/21	Removed future product asterisks from Ordering Information table	22

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